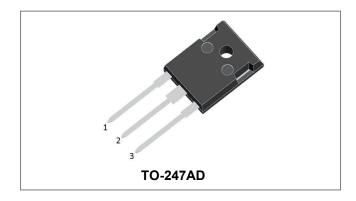


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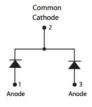
### **MBR30150WT SCHOTTKY RECTIFIER**



### **Features**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	150	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=103°C, rectangular wave form	15(Per Leg) 30(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	408	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.79	1.00	V
(per leg)*	V <sub>F2</sub>	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.63	0.78	V
Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25  ^{\circ}\text{C}$	0.0002	0.1	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_J = 125  ^{\circ}\text{C}$	3	15.0	mA
Junction Capacitance (per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	370	400	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%



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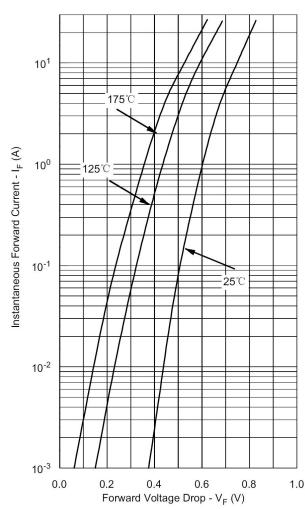


## **Thermal-Mechanical Specifications:**

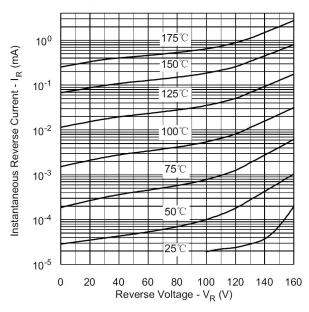
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	ΤJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(per leg)	$R_{ heta JC}$	DC operation	2.1	°C/W
Typical Thermal Resistance Junction to Case(per device)	$R_{ heta JC}$	DC operation	1.1	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0</sub> CS	Mounting surface, smooth and greased	0.24	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AD			

## **Ratings and Characteristics Curves**

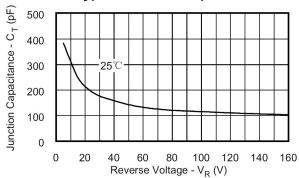
#### **Typical Forward Characteristics**



### **Typical Reverse Characteristics**



#### **Typical Junction Capacitance**



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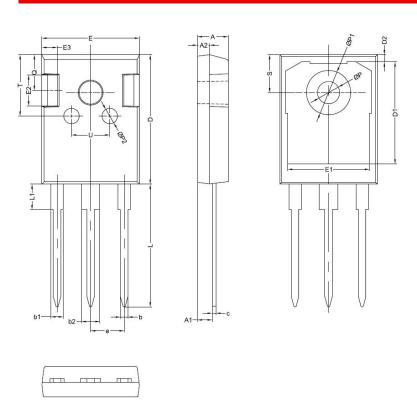


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### **Mechanical Dimensions TO-247AD**



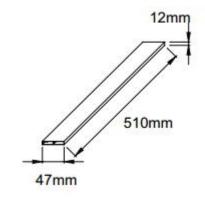
CYMPOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.40	
b1	1.80	2.00	2.20	
b2	2.80	3.00	3.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.55		
D2		1.20		
D2 E	15.45	15.80	16.00	
E1		13.30		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.70	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1		7.40	
P2		2.50		
Q		5.80		
Q S	6.05	6.15	6.25	
T		10.00		
U		6.20		

## **Ordering Information:**

Device	Package	Shipping	
MBR30150WT	TO-247AD(Pb-Free)	25pcs / tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Tube Specification**



## **Marking Diagram**



Where XXXXX is YYWWL

MBR = Device Type 30 = Forward Current (30A) 150 = Reverse Voltage (150V) WT = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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  - http://www.smc-diodes.com sales@ smc-diodes.com •

#### MBR30150WT



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